

# LM5574 75V, 0.5A, Step-Down Switching Regulator

#### 1 Features

- Moved the automotive device to a standalone data sheet (SNOSB22
  - Integrated 75V, 750mΩ N-channel MOSFET
- Ultra-wide input voltage range from 6V to 75V
- Adjustable output voltage as low as 1.225V
- 1.5% feedback reference accuracy
- Operating frequency adjustable between 50kHz and 500kHz with single resistor
- Controller or peripheral frequency synchronization
- Adjustable soft start
- Emulated current mode control architecture
- Wide bandwidth error amplifier
- Built-in protection
- Create a custom design using the LM5574 with the WEBENCH® Power Designer

## 2 Applications

Industrial

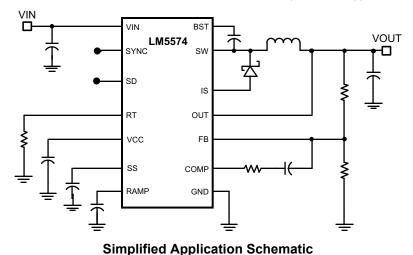
## 3 Description

The LM5574 is an easy-to-use, buck regulator that allows design engineers to design and optimize a robust power supply using a minimum set of components. Operating with an input voltage range of 6V to 75V, the LM5574 delivers 0.5A of continuous output current with an integrated 750mΩ N-Channel MOSFET. The regulator uses an emulated current mode architecture, which provides inherent line regulation, tight load transient response, and ease-ofloop compensation without the usual limitation of lowduty cycles associated with current mode regulators. The operating frequency is adjustable from 50kHz to 500kHz to allow optimization of size and efficiency. To reduce EMI, a frequency synchronization pin allows multiple ICs from the LM(2)557x family to self-synchronize or to synchronize to an external clock. The LM5574 makes sure of robustness with cycle-by-cycle current limit, short-circuit protection, thermal shutdown, and remote shutdown. The device is available in a 16-pin TSSOP package. The LM5574 is supported by the full suite of WEBENCH online design tools.

### **Package Information**

| PART NUMBER | PACKAGE <sup>(1)</sup> | PACKAGE SIZE <sup>(2)</sup> |
|-------------|------------------------|-----------------------------|
| LM5574      | PW (TSSOP, 16)         | 5mm × 6.4mm                 |

- For more information, see Section 10.
- The package size (length × width) is a nominal value and includes pins, where applicable.





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# **4 Pin Configuration and Functions**

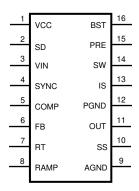


Figure 4-1. PW Package 16-Pin TSSOP (Top View)

**Table 4-1. Pin Functions** 

|                       | PIN  | <b>=</b> \(\pi = (1)\) | PERSONAL PRINTERS   |  |
|-----------------------|------|------------------------|---|--|
| NO.                   | NAME | TYPE <sup>(1)</sup>    | DESCRIPTION   | APPLICATION INFORMATION  |
| 1                     | VCC  | 0                      | Output of the bias regulator  | Vcc monitors Vin up to 9V. Beyond 9V, Vcc is regulated to 7V. A 0.1µF to 1µF ceramic decoupling capacitor is required. An external voltage (7.5V – 14V) can be applied to this pin to reduce internal power dissipation. |
| 2 SD I Shutdown or U\ |      | Shutdown or UVLO input | If the SD pin voltage is less than 0.7V, the regulator is in a low power state. If the SD pin voltage is between 0.7V and 1.225V, the regulator is in standby mode. If the SD pin voltage is more than 1.225V, the regulator is operational. An external voltage divider can be used to set a line undervoltage shutdown threshold. If the SD pin is left open circuit, a 5µA pullup current source configures the regulator fully operational. |  |
| 3                     | Vin  | I                      | Input supply voltage  | Nominal operating range: 6V to 75V   |
| 4                     | SYNC | I                      | Oscillator synchronization input or output  | The internal oscillator can be synchronized to an external clock with an external pulldown device.  Multiple LM5574 devices can be synchronized together by connection of the SYNC pins.                                 |
| 5                     | COMP | 0                      | Output of the internal error amplifier  | The loop compensation network must be connected between this pin and the FB pin.   |
| 6                     | FB   | I                      | Feedback signal from the regulated output   | This pin is connected to the inverting input of the internal error amplifier. The regulation threshold is 1.225V.  |
| 7                     | RT   | I                      | Internal oscillator frequency set input   | The internal oscillator is set with a single resistor connected between this pin and the AGND pin.   |
| 8                     | RAMP | 0                      | Ramp control signal   | An external capacitor connected between this pin and the AGND pin sets the ramp slope used for current mode control. Recommended capacitor range 50pF to 2000pF.   |
| 9                     | AGND | GND                    | Analog ground   | Internal reference for the regulator control functions   |
| 10                    | SS   | 0                      | Soft-start  | An external capacitor and an internal 10µA current source set the time constant for the rise of the error amp reference. The SS pin is held low during standby, Vcc UVLO, and thermal shutdown.                          |
| 11                    | OUT  | 0                      | Output voltage connection   | Connect directly to the regulated output voltage.  |
| 12                    | PGND | GND                    | Power ground  | Low-side reference for the PRE switch and the IS sense resistor.   |



## **Table 4-1. Pin Functions (continued)**

|     | PIN      | TYPE <sup>(1)</sup> | DESCRIPTION                                   | APPLICATION INFORMATION  |  |  |
|-----|----------|---------------------|---|--|--|--|
| NO. | NO. NAME |                     | DESCRIPTION                                   | APPLICATION INFORMATION  |  |  |
| 13  | IS       | I                   | Current sense                                 | Current measurement connection for the recirculating diode. An internal sense resistor and a sample and hold circuit sense the diode current near the conclusion of the off-time. This current measurement provides the DC level of the emulated current ramp.   |  |  |
| 14  | SW       | 0                   | Switching node                                | The source terminal of the internal buck switch. The SW pin must be connected to the external Schottky diode and to the buck inductor.   |  |  |
| 15  | PRE      | 0                   | Pre-charge assist for the bootstrap capacitor | This open-drain output can be connected to SW pin to help charging the bootstrap capacitor during very light load conditions or in applications where the output can be pre-charged before the LM5574 is enabled. An internal pre-charge MOSFET is turned on for 250ns each cycle just prior to the on-time interval of the buck switch. |  |  |
| 16  | BST      | I                   | Boost input for bootstrap capacitor           | An external capacitor is required between the BST and the SW pins. TI recommends a 0.022µF ceramic capacitor. The capacitor is charged from Vcc through an internal diode during the off-time of the buck switch.  |  |  |

<sup>(1)</sup> I = input, O = output, GND = ground

## 5 Specifications

## 5.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)(1)

|                                       | MIN | MAX               | UNIT |
|---------------------------------------|-----|-------------------|------|
| V <sub>IN</sub> to GND                |     | 76                | V    |
| BST to GND                            |     | 90                | V    |
| PRE to GND                            |     | 76                | V    |
| SW to GND (steady-state)              |     | -1.5              | V    |
| BST to V <sub>CC</sub>                |     | 76                | V    |
| SD, V <sub>CC</sub> to GND            |     | 14                | V    |
| BST to SW                             |     | 14                | V    |
| OUT to GND                            |     | Limited to<br>Vin |      |
| SYNC, SS, FB, RAMP to GND             |     | 7                 | V    |
| Storage temperature, T <sub>stg</sub> | -65 | 150               | °C   |

<sup>(1)</sup> Operation outside the Absolute Maximum Ratings may cause permanent device damage. Absolute Maximum Ratings do not imply functional operation of the device at these or any other conditions beyond those listed under Recommended Operating Conditions. If used outside the Recommended Operating Conditions but within the Absolute Maximum Ratings, the device may not be fully functional, and this may affect device reliability, functionality, performance, and shorten the device lifetime.

## 5.2 ESD Ratings

|                    |  |  | VALUE | UNIT |
|--------------------|--|--|-------|------|
|                    |  | Human-body model (HBM), per ANSI/ESDA/JEDEC JS-001 <sup>(1)</sup>              | ±2000 |      |
| V <sub>(ESD)</sub> | Electrostatic discharge <sup>(3)</sup> | Charged-device model (CDM), per JEDEC specification JESD22-C101 <sup>(2)</sup> | ±500  | V    |

- (1) JEDEC document JEP155 states that 500V HBM allows safe manufacturing with a standard ESD control process.
- (2) JEDEC document JEP157 states that 250V CDM allows safe manufacturing with a standard ESD control process
- (3) The human-body model is a 100pF capacitor discharged through a  $1.5k\Omega$  resistor into each pin.

## **5.3 Recommended Operating Conditions**

over operating free-air temperature range (unless otherwise noted)

|                                | MIN | NOM MAX | UNIT |
|--------------------------------|-----|---------|------|
| V <sub>IN</sub>                | 6   | 75      | V    |
| Operation junction temperature | -40 | 125     | °C   |

#### 5.4 Thermal Information

|                       |  | LM5574     |      |
|-----------------------|--|------------|------|
|                       | THERMAL METRIC <sup>(1)</sup>                | PW (TSSOP) | UNIT |
|                       |  | 16 PINS    |      |
| $R_{\theta JA}$       | Junction-to-ambient thermal resistance       | 95         | °C/W |
| R <sub>0JC(top)</sub> | Junction-to-case (top) thermal resistance    | 32         | °C/W |
| $R_{\theta JB}$       | Junction-to-board thermal resistance         | 55         | °C/W |
| $\Psi_{JT}$           | Junction-to-top characterization parameter   | 1.2        | °C/W |
| ΨЈВ                   | Junction-to-board characterization parameter | 54         | °C/W |

<sup>(1)</sup> For more information about traditional and new thermal metrics, see the Semiconductor and IC Package Thermal Metrics application note.



## **5.5 Electrical Characteristics**

Specifications with standard typeface are for  $T_J$  = 25°C,  $V_{IN}$  = 48V,  $R_T$  = 32.4k $\Omega$  unless otherwise stated.<sup>(1)</sup>

|                     | PARAMETER                               | TEST CONDITIONS                                 | MIN   | TYP   | MAX   | UNIT    |
|---------------------|---|---|-------|-------|-------|---------|
| STARTUP REG         | ULATOR                                  |   |       |       | •     |         |
| V <sub>CC</sub> Reg | V <sub>CC</sub> Regulator Output        |   | 6.85  | 7.15  | 7.45  | V       |
|                     | V <sub>CC</sub> LDO Mode turn-off       |   |       | 9     |       | V       |
|                     | V <sub>CC</sub> Current Limit           | V <sub>CC</sub> = 0 V,                          |       | 25    |       | mA      |
| VCC SUPPLY          |   | '   |       |       | '     |         |
|                     | V <sub>CC</sub> UVLO Threshold          | (V <sub>CC</sub> increasing).                   | 5.03  | 5.35  | 5.67  | V       |
|                     | V <sub>CC</sub> Undervoltage Hysteresis |   |       | 0.35  |       | V       |
|                     | Bias Current (lin)                      | FB = 1.3 V.                                     |       | 2     | 4.5   | mA      |
|                     | Shutdown Current (lin)                  | SD = 0 V.                                       |       | 48    | 85    | μA      |
| SHUTDOWN TH         | HRESHOLDS                               | '   |       |       | 1     |         |
|                     | Shutdown Threshold                      | (SD Increasing)                                 | 0.47  | 0.7   | 0.9   | V       |
|                     | Shutdown Hysteresis                     |   |       | 0.1   |       | V       |
|                     | Standby Threshold                       | (Standby Increasing)                            | 1.17  | 1.225 | 1.28  | V       |
|                     | Standby Hysteresis                      |   |       | 0.1   |       | V       |
|                     | SD Pull-up Current Source               |   |       | 5     |       | μA      |
| SWITCH CHAR         | ACTERISTICS                             | 1   |       |       |       |         |
|                     | Buck Switch Rds(on)                     |   |       | 750   | 1500  | mΩ      |
|                     | BOOST UVLO                              |   |       | 4     |       | V       |
|                     | BOOST UVLO Hysteresis                   |   |       | 0.93  |       | V       |
|                     | Pre-charge Switch Rds(on)               |   |       | 70    |       | Ω       |
|                     | Pre-charge Switch on-time               |   |       | 250   |       | ns      |
| CURRENT LIMI        |   |   |       |       |       |         |
|                     | Cycle by Cycle Current Limit            | RAMP = 0 V                                      | 0.6   | 0.7   | 0.8   | A       |
|                     | Cycle by Cycle Current Limit Delay      | RAMP = 2.5 V                                    |       | 75    |       | ns      |
| SOFT-START          |   |   |       |       |       |         |
|                     | SS Current Source                       |   | 7     | 10    | 14    | μA      |
| OSCILLATOR          |   |   |       |       |       | · ·     |
|                     | Frequency1                              |   | 180   | 200   | 220   | kHz     |
|                     | Frequency2                              | $R_T = 11 \text{ k}\Omega$ .                    | 425   | 485   | 525   | kHz     |
|                     | SYNC Source Impedance                   | ·   |       | 11    |       | kΩ      |
|                     | SYNC Sink Impedance                     |   |       | 110   |       | Ω       |
|                     | SYNC Threshold (falling)                |   |       | 1.3   |       | V       |
|                     | SYNC Frequency                          | R <sub>T</sub> = 11 kΩ.                         | 550   |       |       | kHz     |
|                     | SYNC Pulse Width Minimum                |   | 15    |       |       | ns      |
| RAMP GENERA         | ATOR                                    |   |       |       |       |         |
|                     | Ramp Current 1                          | V <sub>IN</sub> = 60 V, V <sub>OUT</sub> =10 V. | 467   | 550   | 633   | μA      |
|                     | Ramp Current 2                          | V <sub>IN</sub> = 10 V, V <sub>OUT</sub> =10 V. | 36    | 50    | 64    | '<br>μΑ |
| PWM COMPAR          |   | 114 7 301                                       |       |       |       | •       |
|                     | Forced Off-time                         |   | 416   | 500   | 575   | ns      |
|                     | Min On-time                             |   |       | 80    |       | ns      |
|                     | COMP to PWM Comparator Offset           |   |       | 0.7   |       | V       |
| ERROR AMPLI         | <u> </u>                                | I   |       | ***   |       | -       |
| <b></b>             | Feedback Voltage                        | Vfb = COMP.                                     | 1.207 | 1.225 | 1.243 | μS      |
|                     | FB Bias Current                         |   |       | 10    |       | nA      |
|                     | DC Gain                                 |   |       | 70    |       | dB      |
|                     | COMP Sink / Source Current              |   | 3     | 70    |       | mA      |
|                     | Unity Gain Bandwidth                    |   |       | 3     |       | MHz     |
|                     | Jinty Gain Banawidin                    |   |       | 9     |       | 1711 12 |



## **5.5 Electrical Characteristics (continued)**

Specifications with standard typeface are for  $T_J$  = 25°C,  $V_{IN}$  = 48V,  $R_T$  = 32.4k $\Omega$  unless otherwise stated.<sup>(1)</sup>

|                    | PARAMETER                   | TEST CONDITIONS | MIN | TYP | MAX | UNIT |
|--------------------|-----------------------------|-----------------|-----|-----|-----|------|
| D <sub>SENSE</sub> |                             |                 |     | 250 |     | mΩ   |
| THERMAL SHUTDON    | WN                          |                 |     |     |     |      |
| Tsd                | Thermal Shutdown Threshold  |                 |     | 165 |     | °C   |
|                    | Thermal Shutdown hysteresis |                 |     | 25  |     | °C   |

<sup>(1)</sup> Min and maximum limits are 100% production tested at 25°C. Limits over the operating temperature range are specified through correlation using Statistical Quality Control (SQC) methods. Limits are used to calculate Texas Instruments Average Outgoing Quality Level (AOQL).



## 5.6 Typical Characteristics

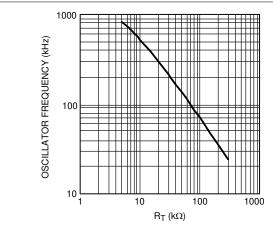


Figure 5-1. Oscillator Frequency vs  $R_T$ 

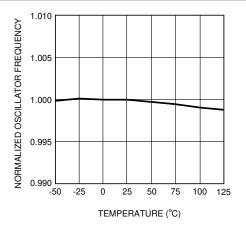


Figure 5-2. Oscillator Frequency vs Temperature  $F_{OSC} = 200kHz$ 

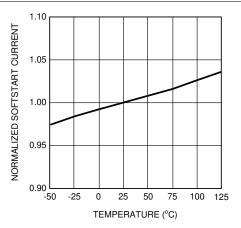


Figure 5-3. Soft-Start Current vs Temperature

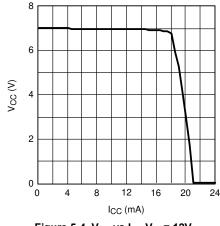


Figure 5-4.  $V_{CC}$  vs  $I_{CC}$   $V_{IN}$  = 12V

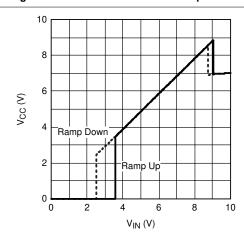


Figure 5-5.  $V_{CC}$  vs  $V_{IN}$   $R_L$  =  $7k\omega$ 

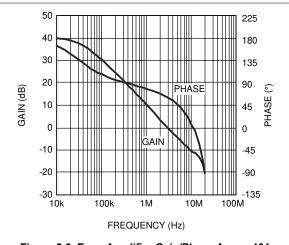
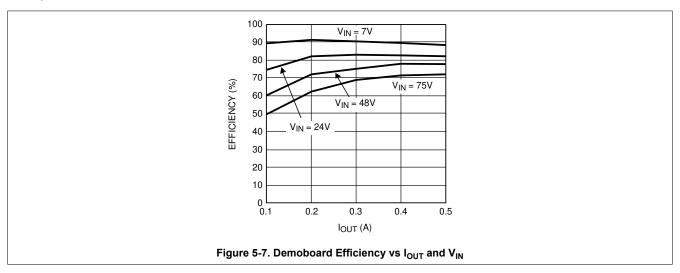


Figure 5-6. Error Amplifier Gain/Phase  $A_{VCL}$  = 101

# **5.6 Typical Characteristics (continued)**



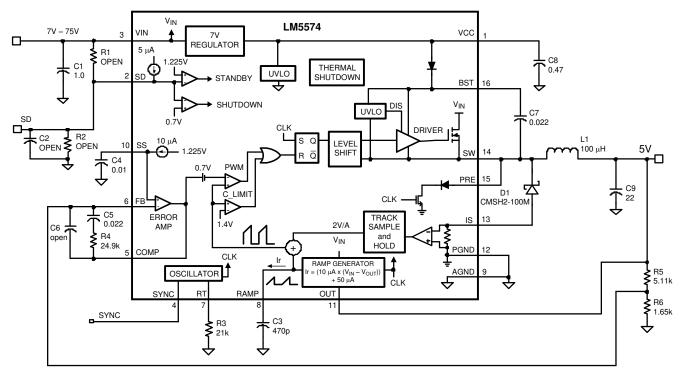
## **6 Detailed Description**

#### 6.1 Overview

The LM5574 switching regulator features the functions necessary to implement an efficient high voltage buck regulator using a minimum of external components. This easy-to-use regulator integrates a 75V, N-Channel buck switch with an output current capability of 0.5 Amps. The regulator control method is based on current mode control using an emulated current ramp. Peak current mode control provides inherent line voltage feed-forward, cycle-by-cycle current limiting, and ease-of-loop compensation. The use of an emulated control ramp reduces noise sensitivity of the pulse width modulation circuit, which allows reliable processing of very small duty cycles necessary in high input voltage applications. The operating frequency is user programmable from 50kHz to 500kHz. An oscillator synchronization pin allows multiple LM5574 regulators to self-synchronize or be synchronized to an external clock. The output voltage can be set as low as 1.225V. Fault protection features include, current limiting, thermal shutdown, and remote shutdown capability. The device is available in the 16-pin TSSOP package.

The functional block diagram and typical application of the LM5574 are shown in #unique\_17/unique\_17\_Connect\_42\_SNVS4788130. The LM5574 can be applied in numerous applications to efficiently step-down a high, unregulated input voltage. The device is designed for telecom, industrial power bus voltage ranges.

## 6.2 Functional Block Diagram



### **6.3 Feature Description**

## 6.3.1 High Voltage Start-Up Regulator

The LM5574 contains a dual-mode internal high voltage start-up regulator that provides the Vcc bias supply for the PWM controller and boot-strap MOSFET gate driver. The input pin (VIN) can be connected directly to the input voltage as high as 75V. For input voltages less than 9V, a low dropout switch connects Vcc directly to Vin. In this supply range, Vcc is approximately equal to Vin. For Vin voltage greater than 9V, the low dropout switch is disabled and the Vcc regulator is enabled to maintain Vcc at approximately 7V. The wide operating range of 6V to 75V is achieved through the use of this dual-mode regulator.

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The output of the Vcc regulator is current limited to 25mA. Upon power up, the regulator sources current into the capacitor connected to the VCC pin. When the voltage at the VCC pin exceeds the Vcc UVLO threshold of 5.35V and the SD pin is greater than 1.225V, the output switch is enabled and a soft-start sequence begins. The output switch remains enabled until Vcc falls below 5.0V or the SD pin falls below 1.125V.

An auxiliary supply voltage can be applied to the Vcc pin to reduce the IC power dissipation. If the auxiliary voltage is greater than 7.3V, the internal regulator essentially shuts off, which reduces the IC power dissipation. The Vcc regulator series pass transistor includes a diode between Vcc and Vin that can not be forward biased in normal operation. Therefore, the auxiliary Vcc voltage can never exceed the Vin voltage.

In high voltage applications, take extra care to make sure the VIN pin does not exceed the absolute maximum voltage rating of 76V. During line or load transients, voltage ringing on the Vin line that exceeds the absolute maximum ratings can damage the IC. Both careful printed-circuit board layout and the use of quality bypass capacitors located close to the VIN and GND pins are essential.

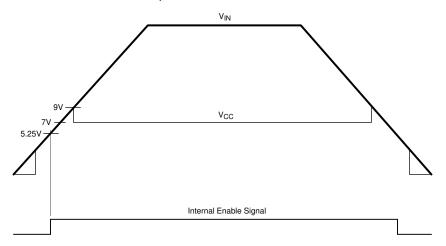


Figure 6-1. Vin and Vcc Sequencing

#### 6.3.2 Oscillator and Sync Capability

The LM5574 oscillator frequency is set by a single external resistor connected between the RT pin and the AGND pin. The  $R_T$  resistor must be placed very close to the device and connected directly to the pins of the IC (RT and AGND). To set a desired oscillator frequency (F), the necessary value for the  $R_T$  resistor can be calculated by Equation 1.

$$R_{T} = \frac{\frac{1}{F} \cdot 580 \times 10^{-9}}{135 \times 10^{-12}} \tag{1}$$

The SYNC pin can be used to synchronize the internal oscillator to an external clock. The external clock must be of *higher frequency* than the free-running frequency set by the  $R_T$  resistor. A clock circuit with an open-drain output is the recommended interface from the external clock to the SYNC pin. The clock pulse duration must be greater than 15ns.



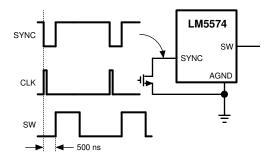


Figure 6-2. Sync From External Clock

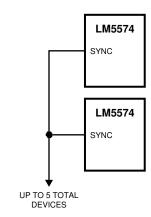


Figure 6-3. Sync From Multiple Devices

Multiple LM5574 devices can be synchronized together simply by connecting the SYNC pins together. In this configuration, all of the devices are synchronized to the highest frequency device. The diagram in Figure 6-4 shows the SYNC input and output features of the LM5574. The internal oscillator circuit drives the SYNC pin with a strong pulldown and weak pullup inverter. When the SYNC pin is pulled low either by the internal oscillator or an external clock, the ramp cycle of the oscillator is terminated and a new oscillator cycle begins. Thus, if the SYNC pins of several LM5574 ICs are connected together, the IC with the highest internal clock frequency pulls the connected SYNC pins low first and terminate the oscillator ramp cycles of the other ICs. The LM5574 with the highest programmed clock frequency serve as the controller and control the switching frequency of the all the devices with lower oscillator frequency.

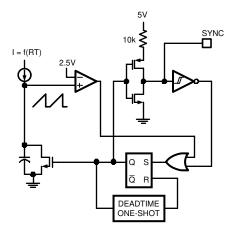


Figure 6-4. Simplified Oscillator Block Diagram and Sync I/O Circuit

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## 6.3.3 Error Amplifier and PWM Comparator

The internal high gain error amplifier generates an error signal proportional to the difference between the regulated output voltage and an internal precision reference (1.225V). The output of the error amplifier is connected to the COMP pin allowing the user to provide loop compensation components, generally a type II network, as shown in #unique\_17/unique\_17\_Connect\_42\_SNVS4788130. This network creates a pole at DC, a zero and a noise-reducing, high-frequency pole. The PWM comparator compares the emulated current sense signal from the RAMP generator to the error amplifier output voltage at the COMP pin.

### 6.3.4 Ramp Generator

The ramp signal used in the pulse width modulator for current mode control is typically derived directly from the buck switch current. This switch current corresponds to the positive slope portion of the output inductor current. Using this signal for the PWM ramp simplifies the control loop transfer function to a single pole response and provides inherent input voltage feed-forward compensation. The disadvantage of using the buck switch current signal for PWM control is the large leading edge spike due to circuit parasitics that must be filtered or blanked. Also, the current measurement can introduce significant propagation delays. The filtering, blanking time, and propagation delay limit the minimum achievable pulse width. In applications where the input voltage can be relatively large in comparison to the output voltage, controlling small pulse widths and duty cycles is necessary for regulation. The LM5574 uses a unique ramp generator, which does not actually measure the buck switch current but rather reconstructs the signal. Reconstructing or emulating the inductor current provides a ramp signal to the PWM comparator that is free of leading edge spikes and measurement or filtering delays. The current reconstruction is comprised of two elements: a sample and hold DC level and an emulated current ramp.

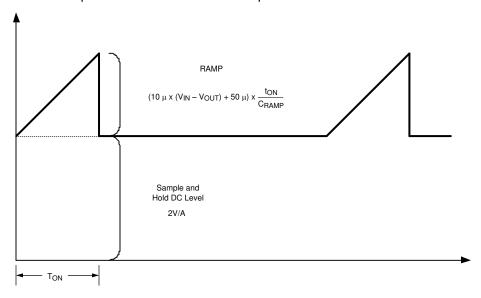


Figure 6-5. Composition of Current Sense Signal

The sample and hold DC level shown in Figure 6-5 is derived from a measurement of the recirculating Schottky diode anode current. The recirculating diode anode must be connected to the IS pin. The diode current flows through an internal current sense resistor between the IS and PGND pins. The voltage level across the sense resistor is sampled and held just prior to the onset of the next conduction interval of the buck switch. The diode current sensing and the sample and hold provide the DC level of the reconstructed current signal. The positive slope inductor current ramp is emulated by an external capacitor connected from the RAMP pin to AGND and an internal voltage controlled current source. The ramp current source that emulates the inductor current is a function of the Vin and Vout voltages per Equation 2.

$$I_{RAMP} = (10\mu \times (Vin - Vout)) + 50\mu A \tag{2}$$

Proper selection of the RAMP capacitor depends upon the selected value of the output inductor. The value of  $C_{RAMP}$  can be selected from Equation 3.



$$C_{RAMP} = L \times 5 \times 10^{-6} \tag{3}$$

where

L is the value of the output inductor in Henrys.

With this value, the scale factor of the emulated current ramp is approximately equal to the scale factor of the DC level sample and hold (2.0V/A). The  $C_{RAMP}$  capacitor must be placed very close to the device and connected directly to the pins of the IC (RAMP and AGND).

For duty cycles greater than 50%, peak current mode control circuits are subject to sub-harmonic oscillation. Sub-harmonic oscillation is normally characterized by observing alternating wide and narrow pulses at the switch node. Add a fixed slope voltage ramp (slope compensation) to the current sense signal to prevent this oscillation. The  $50\mu A$  of offset current provided from the emulated current source adds some fixed slope to the ramp signal. In some high output voltage, high duty cycle applications, additional slope can be required. In these applications, a pullup resistor can be added between the  $V_{CC}$  and RAMP pins to increase the ramp slope compensation.

For  $V_{OUT} > 7.5V$ :

Calculate slope current that is an excellent choice,  $I_{OS} = V_{OUT} \times 10 \mu A/V$ .

For example, at  $V_{OUT} = 10V$ ,  $I_{OS} = 100\mu A$ .

Use Equation 4 to install a resistor from the RAMP pin to V<sub>CC</sub>.

$$R_{RAMP} = V_{CC} / (I_{OS} - 50\mu A)$$

$$VCC \longrightarrow R_{RAMP}$$

$$RAMP \longrightarrow C_{RAMP}$$

$$C_{RAMP}$$

$$C_{RAMP}$$

$$C_{RAMP}$$

Figure 6-6. R to V for  $V > 7.5V_{RAMP\ CC\ OUT}$ 

#### 6.3.5 Maximum Duty Cycle, Input Dropout Voltage

There is a forced off-time of 500ns implemented each cycle to make sure of sufficient time for the diode current to be sampled. This forced off-time limits the maximum duty cycle of the buck switch. The maximum duty cycle varies with the operating frequency.

$$D_{MAX} = 1 - Fs \times 500 ns \tag{5}$$

where

· Fs is the oscillator frequency.

Limiting the maximum duty cycle raises the input dropout voltage. The input dropout voltage is the lowest input voltage required to maintain regulation of the output voltage. Use Equation 6 to calculate an approximation of the input dropout voltage is:

$$Vin_{MIN} = \frac{Vout + V_D}{1 - Fs \times 500 \text{ ns}}$$
 (6)

where

V<sub>D</sub> is the voltage drop across the re-circulatory diode.

Operating at high switching frequency raises the minimum input voltage necessary to maintain regulation.

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#### 6.3.6 Current Limit

The LM5574 contains a unique current monitoring scheme for control and overcurrent protection. When set correctly, the emulated current sense signal provides a signal which is proportional to the buck switch current with a scale factor of 2.0V/A. The emulated ramp signal is applied to the current limit comparator. If the emulated ramp signal exceeds 1.4V (0.7A), the present current cycle is terminated (cycle-by-cycle current limiting). In applications with small output inductance and high input voltage the switch current can overshoot due to the propagation delay of the current limit comparator. If an overshoot occurs, the diode current sampling circuit detects the excess inductor current during the off-time of the buck switch. If the sample and hold DC level exceeds the 1.4V current limit threshold, the buck switch is disabled and skip pulses until the diode current-sampling circuit detects the inductor current has decayed below the current limit threshold. This approach prevents current runaway conditions due to propagation delays or inductor saturation because the inductor current is forced to decay following any current overshoot.

#### 6.3.7 Soft Start

The soft-start feature allows the regulator to gradually reach the initial steady-state operating point, thus reducing start-up stresses and surges. The internal soft-start current source, set to  $10\mu\text{A}$ , gradually increases the voltage of an external soft-start capacitor connected to the SS pin. The soft-start capacitor voltage is connected to the reference input of the error amplifier. Various sequencing and tracking schemes can be implemented using external circuits that limit or clamp the voltage level of the SS pin.

In the event a fault is detected (overtemperature, Vcc UVLO, SD) the soft-start capacitor is discharged. When the fault condition is no longer present a new soft-start sequence commences.

#### 6.3.8 Boost Pin

The LM5574 integrates an N-Channel buck switch and associated floating high voltage level shift, gate driver. This gate driver circuit works in conjunction with an internal diode and an external bootstrap capacitor. The recommends a 0.022µF ceramic capacitor, connected with short traces between the BST pin and SW pin. During the off-time of the buck switch, the SW pin voltage is approximately –0.5V and the bootstrap capacitor is charged from the Vcc through the internal bootstrap diode. When operating with a high PWM duty cycle, the buck switch is forced off each cycle for 500ns to make sure that the bootstrap capacitor is recharged.

Under very light load conditions or when the output voltage is pre-charged, the SW voltage does not remain low during the off-time of the buck switch. If the inductor current falls to zero and the SW pin rises, the bootstrap capacitor does not receive sufficient voltage to operate the buck switch gate driver. For these applications, the PRE pin can be connected to the SW pin to pre-charge the bootstrap capacitor. The internal pre-charge MOSFET and diode connected between the PRE pin and PGND turns on each cycle for 250ns just prior to the onset of a new switching cycle. If the SW pin is at a normal negative voltage level (continuous conduction mode), then no current flows through the pre-charge MOSFET/diode.

#### 6.3.9 Thermal Protection

Internal thermal shutdown circuitry is provided to protect the integrated circuit in the event the maximum junction temperature is exceeded. When activated, typically at 165°C the controller is forced into a low power reset state, disabling the output driver and the bias regulator. This feature is provided to prevent catastrophic failures from accidental device overheating.

### **6.4 Device Functional Modes**

The LM5574 contains a dual-level Shutdown (SD) circuit. When the SD pin voltage is less than 0.7V, the regulator is in a low current shutdown mode. When the SD pin voltage is greater than 0.7V but less than 1.225V, the regulator is in standby mode. In standby mode, the Vcc regulator is active but the output switch is disabled. When the SD pin voltage exceeds 1.225V, the output switch is enabled and normal operation begins. An internal 5µA pullup current source configures the regulator to be fully operational if the SD pin is left open.

An external set-point voltage divider from VIN to GND can be used to set the operational input range of the regulator. The divider must be designed such that the voltage at the SD pin is greater than 1.225V when Vin is in the desired operating range. The internal  $5\mu$ A pullup current source must be included in calculations of



the external set-point divider. Hysteresis of 0.1V is included for both the shutdown and standby thresholds. The SD pin is internally clamped with a  $1k\Omega$  resistor and an 8V Zener clamp. The voltage at the SD pin can never exceed 14V. If the voltage at the SD pin exceeds 8V, the bias current increases at a rate of 1mA/V.

The SD pin can also be used to implement various remote enable, disable functions. Pulling the SD pin below the 0.7V threshold totally disables the controller. If the SD pin voltage is above 1.225V, the regulator is operational.

## 7 Application and Implementation

#### **Note**

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes, as well as validating and testing their design implementation to confirm system functionality.

## 7.1 Application Information

The LM5574 is a step-down DC/DC converter, typically used to convert a higher DC voltage to a lower DC voltage with a maximum output current of 0.5A. The following design procedure can be used to select components for the LM5574.

## 7.2 Typical Application

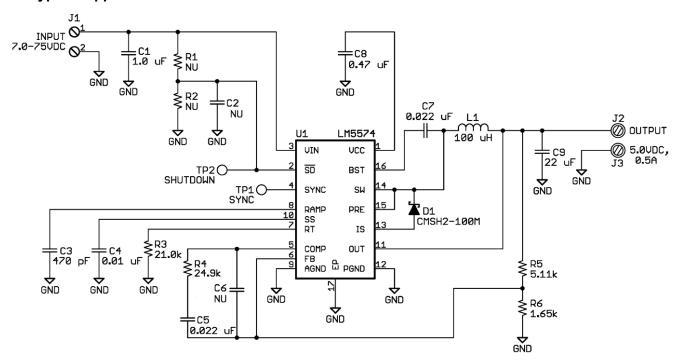


Figure 7-1. LM5574 Reference Schematic

### 7.2.1 Design Requirements

The circuit shown in Section 6.2 is configured for the following specifications:

- V<sub>OUT</sub> = 5V
- V<sub>IN</sub> = 7V to 75V
- Fs = 300kHz
- Minimum load current (for CCM) = 100mA
- Maximum load current = 0.5A

### 7.2.2 Detailed Design Procedure

#### 7.2.2.1 Custom Design With WEBENCH® Tools

Click here to create a custom design using the LM5574 device with the WEBENCH® Power Designer.

- 1. Start by entering the input voltage  $(V_{IN})$ , output voltage  $(V_{OUT})$ , and output current  $(I_{OUT})$  requirements.
- 2. Optimize the design for key parameters such as efficiency, footprint, and cost using the optimizer dial.
- 3. Compare the generated design with other possible solutions from Texas Instruments.

The WEBENCH Power Designer provides a customized schematic along with a list of materials with real-time pricing and component availability.

In most cases, these actions are available:

- Run electrical simulations to see important waveforms and circuit performance
- Run thermal simulations to understand board thermal performance
- Export customized schematic and layout into popular CAD formats
- Print PDF reports for the design, and share the design with colleagues

Get more information about WEBENCH tools at www.ti.com/WEBENCH.

### 7.2.2.2 External Components

The procedure for calculating the external components is shown with the following design example. The following table lists the bill of materials for this design.

| I7 | ЕМ | VALUE          |                              |              |
|----|----|----------------|------------------------------|--------------|
| С  | 1  | C3225X7R2A105M | CAPACITOR, CER, TDK          | 1μ, 100V     |
| С  | 2  | OPEN           | NOT USED                     |              |
| С  | 3  | C0805A471K1GAC | CAPACITOR, CER, KEMET        | 470p, 100V   |
| С  | 4  | C2012X7R2A103K | CAPACITOR, CER, TDK          | 0.01µ, 100V  |
| С  | 5  | C2012X7R2A223K | CAPACITOR, CER, TDK          | 0.022µ, 100V |
| С  | 6  | OPEN           | NOT USED                     |              |
| С  | 7  | C2012X7R2A223K | CAPACITOR, CER, TDK          | 0.022µ, 100V |
| С  | 8  | C2012X7R1C474M | CAPACITOR, CER, TDK          | 0.47µ, 16V   |
| С  | 9  | C3225X7R1C226M | CAPACITOR, CER, TDK          | 22µ, 16V     |
| D  | 1  | CMSH2-100M     | DIODE, 100V, CENTRAL         |              |
| L  | 1  | DR74-101       | INDUCTOR, COOPER             | 100µH        |
| R  | 1  | OPEN           | NOT USED                     |              |
| R  | 2  | OPEN           | NOT USED                     |              |
| R  | 3  | CRCW08052102F  | RESISTOR                     | 21kΩ         |
| R  | 4  | CRCW08052492F  | RESISTOR                     | 24.9kΩ       |
| R  | 5  | CRCW08055111F  | RESISTOR                     | 5.11kΩ       |
| R  | 6  | CRCW08051651F  | RESISTOR                     | 1.65kΩ       |
| U  | 1  | LM5574         | REGULATOR, TEXAS INSTRUMENTS |              |

Table 7-1 5V 0.5A Demo Board Bill of Materials

## 7.2.2.3 R3 (R)<sub>T</sub>

R<sub>T</sub> sets the oscillator switching frequency. Generally, higher frequency applications are smaller but have higher losses. Operation at 300kHz was selected for this example as a reasonable compromise for both small size and high efficiency. Use the following equation to calculate the value of R<sub>T</sub> for 300kHz switching frequency:

$$R_{T} = \frac{\left[ (1/300 \times 10^{3}) - 580 \times 10^{-9} \right]}{135 \times 10^{-12}}$$
 (7)

Product Folder Links: LM5574

The nearest standard value of  $21k\Omega$  was chosen for  $R_T$ .

#### 7.2.2.4 L1-Inductor

The inductor value is determined based on the operating frequency, load current, ripple current, and the minimum and maximum input voltage  $(V_{IN(min)}, V_{IN(max)})$ .

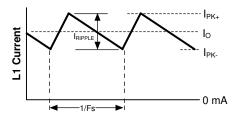


Figure 7-2. Inductor Current Waveform

To keep the circuit in continuous conduction mode (CCM), the maximum ripple current  $I_{RIPPLE}$  must be less than twice the minimum load current, or 0.2Ap-p. With this value of ripple current, use Equation 8 and Equation 9 to calculate the value of inductor (L1).

$$L1 = \frac{V_{OUT} \times (V_{IN(max)} - V_{OUT})}{I_{RIPPLE} \times F_S \times V_{IN(max)}}$$
(8)

$$L1 = \frac{5V \times (75V - 5V)}{0.2A \times 300 \text{ kHz} \times 75V} = 78 \text{ }\mu\text{H}$$
(9)

This procedure provides a guide to select the value of L1. The nearest standard value ( $100\mu H$ ) is used. L1 must be rated for the peak current ( $I_{PK+}$ ) to prevent saturation. During normal loading conditions, the peak current occurs at maximum load current plus maximum ripple. During an overload condition the peak current is limited to 0.7A nominal (0.85A maximum). The selected inductor (see Table 7-1) has a conservative 1.0Amp saturation current rating. For this manufacturer, the saturation rating is defined as the current necessary for the inductance to reduce by 30%, at 20°C.

## 7.2.2.5 C3 (C)<sub>RAMP</sub>

With the inductor value selected, use Equation 10 to calculate the value of C3 ( $C_{RAMP}$ ) necessary for the emulation ramp circuit.

$$C_{RAMP} = L \times 5 \times 10^{-6}$$
 (10)

where

· L is in Henrys

With L1 selected for 100µH, the recommended value for C3 is 470pF (nearest standard value).

#### 7.2.2.6 C9-Output Capacitor

The output capacitor, C9 smooths the inductor ripple current and provides a source of charge for transient loading conditions. For this design, a 22µF ceramic capacitor was selected. The ceramic capacitor provides ultra-low ESR to reduce the output ripple voltage and noise spikes. Use Equation 11 to calculate an approximation for the output ripple voltage.

$$\Delta V_{OUT} = \Delta I_L \times \left( ESR + \frac{1}{8 \times F_S \times C_{OUT}} \right)$$
(11)

#### 7.2.2.7 D1-Async Diode

A Schottky type re-circulating diode is required for all LM5574 applications. TI does not recommend ultra-fast diodes and ultra-fast diodes can result in damage to the IC due to reverse recovery current transients. The near excellent choice reverse recovery characteristics and low forward voltage drop are particularly important diode characteristics for high input voltage and low output voltage applications common to the LM5574. The reverse recovery characteristic determines how long the current surge lasts each cycle when the buck switch is turned on. The reverse recovery characteristics of Schottky diodes minimize the peak instantaneous power in the buck switch occurring during turn-on each cycle. The resulting switching losses of the buck switch are significantly reduced when using a Schottky diode. The reverse breakdown rating must be selected for the maximum V<sub>IN</sub>, plus some safety margin.

The forward voltage drop has a significant impact on the conversion efficiency, especially for applications with a low output voltage. Rated current for diodes vary widely from various manufacturers. The worst case is to assume a short-circuit load condition. In this case, the diode carries the output current almost continuously. For the LM5574, this current can be as high as 0.7A. Assuming a worst-case, 1V drop across the diode, the maximum diode power dissipation can be as high as 0.7W. For the reference design, a 100V Schottky in an SMA package was selected.

#### 7.2.2.8 C1-Input Capacitor

The regulator supply voltage has a large source impedance at the switching frequency. Good-guality input capacitors are necessary to limit the ripple voltage at the VIN pin while supplying most of the switch current during the on-time. When the buck switch turns on, the current into the VIN pin steps to the lower peak of the inductor current waveform, ramps up to the peak value, then drops to zero at turn-off. The average current into VIN during the on-time is the load current. The input capacitance must be selected for RMS current rating and minimum ripple voltage. A good approximation for the required ripple current rating necessary is I<sub>RMS</sub> > I<sub>OLIT</sub> / 2.

Quality ceramic capacitors with a low ESR must be selected for the input filter. To allow for capacitor tolerances and voltage effects, one 1.0µF, 100V ceramic capacitor is used. If step input voltage transients are expected near the maximum rating of the LM5574, a careful evaluation of ringing and possible spikes at the device VIN pin must be completed. An additional damping network or input voltage clamp can be required in these cases.

#### 7.2.2.9 C8-VCC Capacitor

The capacitor at the VCC pin provides noise filtering and stability for the V<sub>CC</sub> regulator. The recommended value of C8 can be no smaller than 0.1μF, and must be a good-quality, low-ESR, ceramic capacitor. A value of 0.47μF was selected for this design.

#### 7.2.2.10 C7-BST Capacitor

The bootstrap capacitor between the BST and the SW pins supplies the gate current to charge the buck switch gate at turn-on. The recommended value of C7 is 0.022µF and must be a good-quality, low-ESR, ceramic capacitor.

### 7.2.2.11 C4- SS Capacitor

The capacitor at the SS pin determines the soft-start time, that is, the time for the reference voltage and the output voltage, to reach the final regulated value. Equation 12 determines the time.

$$t_{ss} = \frac{C4 \times 1.225 V}{10 \,\mu\text{A}} \tag{12}$$

For this application, a C4 value of 0.01µF was chosen which corresponds to a soft-start time of 1ms.

#### 7.2.2.12 R5, R6- Feedback Resistors

R5 and R6 set the output voltage level. Use Equation 13 to calculate the ratio of these resistors.

$$R5/R6 = (V_{OUT} / 1.225V) - 1 \tag{13}$$

Product Folder Links: LM5574

For a 5V output, the R5/R6 ratio calculates to 3.082. The resistors must be chosen from standard value resistors. A good starting point is selection in the range of  $1.0k\Omega$  to  $10k\Omega$ . Values of  $5.11k\Omega$  for R5, and  $1.65k\Omega$  for R6 were selected.

#### 7.2.2.13 R1, R2, C2-SD Pin Components

A voltage divider can be connected to the SD pin to set a minimum operating voltage  $Vin_{(min)}$  for the regulator. If this feature is required, the easiest approach to select the divider resistor values is to select a value for R1 (TI recommends between  $10k\Omega$  and  $100k\Omega$ ) then calculate R2 from Equation 14.

R2 = 1.225 x 
$$\left(\frac{R1}{V_{IN(min)} + (5 \times 10^{-6} \times R1) - 1.225}\right)$$
 (14)

Capacitor C2 provides filtering for the divider. The voltage at the SD pin can never exceed 8V. When using an external set-point divider, clamping the SD pin at high input voltage conditions can be necessary. The reference design uses the full range of the LM5574 (6V to 75V); therefore, these components can be omitted. With the SD pin open circuit, the LM5574 responds after the Vcc UVLO threshold is satisfied.

### 7.2.2.14 R4, C5, C6-Compensation Components

These components configure the error amplifier gain characteristics to accomplish a stable overall loop gain. One advantage of current mode control is the ability to close the loop with only two feedback components: R4 and C5. The overall loop gain is the product of the modulator gain and the error amplifier gain. The DC modulator gain of the LM5574 is Equation 15.

$$DC Gain_{(MOD)} = G_{m(MOD)} \times R_{LOAD} = 0.5 \times R_{LOAD}$$
(15)

The dominant low frequency pole of the modulator is determined by the load resistance ( $R_{LOAD}$ ,) and output capacitance ( $C_{OLT}$ ). The corner frequency of this pole is Equation 16.

$$f_{p(MOD)} = 1 / (2\pi R_{LOAD} C_{OUT})$$
(16)

For  $R_{LOAD} = 20\Omega$  and  $C_{OUT} = 22\mu F$  then  $f_{p(MOD)} = 362Hz$ 

DC  $Gain_{(MOD)} = 0.5 \times 20 = 20dB$ 

For the design example of #unique\_17/unique\_17\_Connect\_42\_SNVS4788130, Figure 7-3 shows the measured modulator gain vs frequency characteristic.

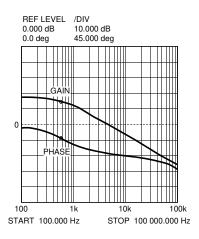


Figure 7-3. Gain and Phase Of Modulator R =  $20\Omega$  and C =  $22\mu f_{LOAD\ OUT}$ 

Components R4 and C5 configure the error amplifier as a type II configuration which has a pole at DC and a zero at  $f_Z = 1 / (2\pi R4C5)$ . The error amplifier zero cancels the modulator pole and leaves a single pole response at the crossover frequency of the loop gain. A single pole response at the crossover frequency yields a very stable loop with 90 degrees of phase margin.

For the design example, a target loop bandwidth (crossover frequency) of 25kHz was selected. The compensation network zero ( $f_Z$ ) must be selected at least an order of magnitude less than the target crossover frequency. This requirement constrains the product of R4 and C5 for a desired compensation network zero 1 / ( $2\pi$  R4 C5) to be less than 2kHz. Increasing R4, while proportionally decreasing C5, increases the error amp gain. Conversely, decreasing R4 while proportionally increasing C5 decreases the error amp gain. For the design example, C5 was selected for  $0.022\mu F$  and R4 was selected for  $24.9k\Omega$ . These values configure the compensation network zero at 290Hz. The error amp gain at frequencies greater than  $f_Z$  is: R4 / R5, which is approximately 5 (14dB).

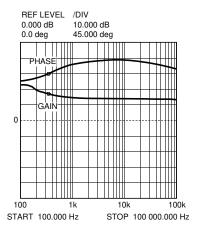


Figure 7-4. Error Amplifier Gain and Phase

The overall loop can be predicted as the sum (in dB) of the modulator gain and the error amp gain.

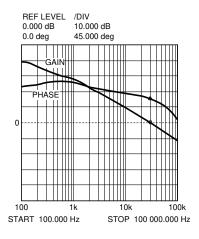


Figure 7-5. Overall Loop Gain and Phase

If a network analyzer is available, the modulator gain can be measured and the error amplifier gain can be configured for the desired loop transfer function. If a network analyzer is not available, the error amplifier compensation components can be designed with the guidelines given. Step load transient tests can be performed to verify acceptable performance. The step load goal is minimum overshoot with a damped response.

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C6 can be added to the compensation network to decrease noise susceptibility of the error amplifier. The value of C6 must be sufficiently small because the addition of this capacitor adds a pole in the error amplifier transfer function. This pole must be well beyond the loop crossover frequency. A good approximation of the location of the pole added by C6 is:  $f_{p2} = fz \times C5 / C6$ .

#### 7.2.2.15 Bias Power Dissipation Reduction

Buck regulators operating with high input voltage can dissipate an appreciable amount of power for the bias of the IC. The  $V_{CC}$  regulator must step-down the input voltage  $V_{IN}$  to a nominal  $V_{CC}$  level of 7V. The large voltage drop across the  $V_{CC}$  regulator translates into a large power dissipation within the  $V_{CC}$  regulator. There are several techniques that can significantly reduce this bias regulator power dissipation. Figure 7-6 and Figure 7-7 depict two methods to bias the IC from the output voltage. In each case the internal  $V_{CC}$  regulator is used to initially bias the VCC pin. After the output voltage is established, the VCC pin potential is raised above the nominal 7V regulation level, which effectively disables the internal  $V_{CC}$  regulator. The voltage applied to the VCC pin must never exceed 14V. The  $V_{CC}$  voltage must never be larger than the  $V_{IN}$  voltage.

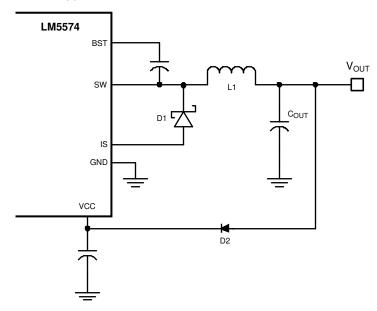


Figure 7-6. Vcc Bias From Vout for 8V < Vout < 14V

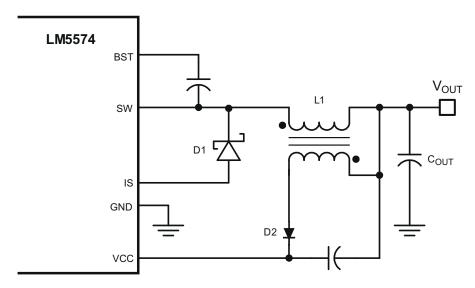
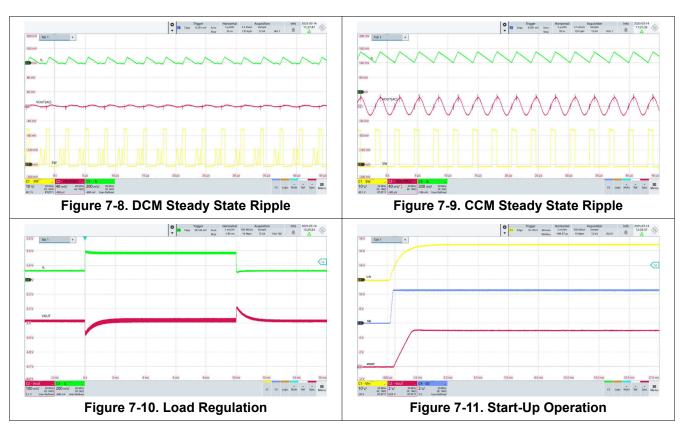


Figure 7-7. Vcc Bias With Additional Winding on the Output Inductor

### 7.2.3 Application Curves

The following characteristics apply to the circuit shown in Figure 7-1. These parameters are not tested and represent typical performance only. Unless otherwise stated, the following conditions apply: VIN = 24V, TA = 25°C.



## 7.3 Power Supply Recommendations

The characteristics of the input supply must be compatible with the specifications found in this data sheet. In addition, the input supply must be capable of delivering the required input current to the loaded regulator. The average input current can be estimated with the following equation

$$I_{IN} = \frac{V_{OUT} \times I_{OUT}}{V_{IN} \times \eta} \tag{17}$$

Where

 $\eta$  is the efficiency.

If the regulator is connected to the input supply through long wires or PCB traces, special care is required to achieve good performance. The parasitic inductance and resistance of the input cables can have an adverse effect on the operation of the regulator. The parasitic inductance, in combination with the low-ESR, ceramic input capacitors, can form an underdamped resonant circuit, resulting in overvoltage transients at the input to the regulator. The parasitic resistance can cause the voltage at the VIN pin to dip whenever a load transient is applied to the output. If the application is operating close to the minimum input voltage, this dip can cause the regulator to momentarily shut down and reset. The best way to solve these kinds of issues is to limit the distance from the input supply to the regulator or plan to use an aluminum or tantalum input capacitor in parallel with the ceramics. The moderate ESR of these types of capacitors help dampen the input resonant circuit and reduce any overshoots. A value in the range of  $20\mu\text{F}$  to  $100\mu\text{F}$  is usually sufficient to provide input damping and help to hold the input voltage steady during large load transients.

Sometimes, for other system considerations, an input filter is used in front of the regulator. This action can lead to instability, as well as some of the effects mentioned above, unless designed carefully. *The AN-2162 Simple Success With Conducted EMI From DC/DC Converters* application note provides helpful suggestions when designing an input filter for any switching regulator.

In some cases, a transient voltage suppressor (TVS) is used on the input of regulators. One class of this device has a snap-back characteristic (thyristor type). TI does not recommend the use of a device with this type of characteristic. When the TVS fires, the clamping voltage falls to a very low value. If this voltage is less than the output voltage of the regulator, the output capacitors discharge through the device back to the input. This uncontrolled current flow can damage the device.

## 7.4 Layout

### 7.4.1 Layout Guidelines

The circuit in #unique\_17/unique\_17\_Connect\_42\_SNVS4788130 serves as both a block diagram of the LM5574 and a typical application board schematic for the LM5574. In a buck regulator, there are two loops where currents are switched very fast. The first loop starts from the input capacitors, to the regulator VIN pin, to the regulator SW pin, to the inductor, and then out to the load. The second loop starts from the output capacitor ground, to the regulator PGND pins, to the regulator IS pins, to the diode anode, to the inductor, and then out to the load. Minimize the loop area of these two loops to reduce the stray inductance and minimize the noise and possible erratic operation. TI recommends a ground plane in the printed-circuit board (PCB) as a means to connect the input filter capacitors to the output filter capacitors and the PGND pins of the regulator. Connect all of the low power ground connections (C<sub>SS</sub>, R<sub>T</sub>, C<sub>RAMP</sub>) directly to the regulator AGND pin. Connect the AGND and PGND pins together through the topside copper trace. Place several vias in this trace to the ground plane.

The two highest power dissipating components are the re-circulating diode and the LM5574 regulator IC. The easiest method to determine the power dissipated within the LM5574 is to measure the total conversion losses (Pin – Pout) then subtract the power losses in the Schottky diode, output inductor and snubber resistor. Use Equation 18 to calculate an approximation for the Schottky diode loss.

$$P = (1 - D) \times lout \times Vfwd$$
 (18)

Use Equation 19 to calculate an approximation for the output inductor power is

$$P = I_{OUT}^2 \times R \times 1.1 \tag{19}$$

### where

- · R is the DC resistance of the inductor
- and the 1.1 factor is an approximation for the AC losses.

If a snubber is used, use Equation 20 to calculate an approximation for the damping resistor power dissipation.

$$P = Vin^2 \times Fsw \times Csnub$$
 (20)

#### where

- Fsw is the switching frequency
- and Csnub is the snubber capacitor.



### 7.4.2 Layout Example

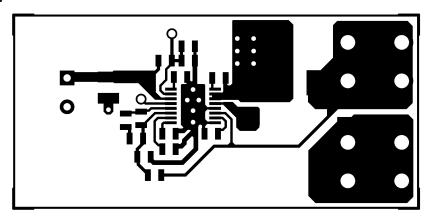


Figure 7-12. Component Side

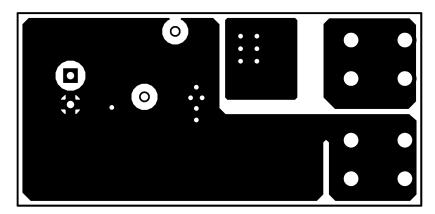


Figure 7-13. Solder Side

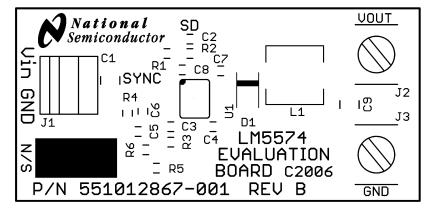


Figure 7-14. Silkscreen

## 7.4.3 Power Dissipation

The most significant variables that affect the power dissipated by the LM5574 are the output current, input voltage, and operating frequency. The power dissipated while operating near the maximum output current and maximum input voltage can be appreciable. The operating frequency of the LM5574 evaluation board has been designed for 300kHz. When operating at 0.5A output current with a 70V input, the power dissipation of the LM5574 regulator is approximately 0.6W.

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#### 7.4.4 Thermal Considerations

The junction-to-ambient thermal resistance of the LM5574 varies with the application. The most significant variables are the area of copper in the PCB and the amount of forced air cooling provided. The junction-to-ambient thermal resistance of the LM5574 mounted in the evaluation board varies from  $90^{\circ}$ C/W with no airflow to  $60^{\circ}$ C/W with 900 LFM (Linear Feet per Minute). With a  $25^{\circ}$ C ambient temperature and no airflow, the predicted junction temperature for the LM5574 is  $25 + ((90 \times 0.6) = 79^{\circ}$ C. If the evaluation board is operated at 0.5A output current, 70V input voltage and high ambient temperature for a prolonged period of time the thermal shutdown protection within the IC can activate. The IC turns off to allow the junction to cool, followed by restart with the soft-start capacitor reset to zero.

## 8 Device and Documentation Support

## 8.1 Device Support

## 8.1.1 Third-Party Products Disclaimer

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## 8.1.2 Development Support

#### 8.1.2.1 Custom Design With WEBENCH® Tools

Click here to create a custom design using the LM5574 device with the WEBENCH® Power Designer.

- 1. Start by entering the input voltage  $(V_{IN})$ , output voltage  $(V_{OUT})$ , and output current  $(I_{OUT})$  requirements.
- 2. Optimize the design for key parameters such as efficiency, footprint, and cost using the optimizer dial.
- 3. Compare the generated design with other possible solutions from Texas Instruments.

The WEBENCH Power Designer provides a customized schematic along with a list of materials with real-time pricing and component availability.

In most cases, these actions are available:

- Run electrical simulations to see important waveforms and circuit performance
- Run thermal simulations to understand board thermal performance
- Export customized schematic and layout into popular CAD formats
- · Print PDF reports for the design, and share the design with colleagues

Get more information about WEBENCH tools at www.ti.com/WEBENCH.

## 8.2 Documentation Support

#### 8.2.1 Related Documentation

For related documentation, see the following:

Texas Instruments, The AN-2162 Simple Success With Conducted EMI From DC/DC Converters application note

#### 8.3 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on ti.com. Click on *Notifications* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

## 8.4 Support Resources

TI E2E<sup>™</sup> support forums are an engineer's go-to source for fast, verified answers and design help — straight from the experts. Search existing answers or ask your own question to get the quick design help you need.

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## 8.6 Electrostatic Discharge Caution



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

## 8.7 Glossary

TI Glossary

This glossary lists and explains terms, acronyms, and definitions.

## 9 Revision History

| <ul> <li>Updated the numbering format for tables, figures, and cross-references throughout the document.</li> <li>Deleted SIMPLE SWITCHER® branding from the data sheet.</li> <li>Changed all instances of legacy terminology to controller and peripheral.</li> <li>Added WEBENCH links</li></ul>  | Page   |                |
|---|--|----------------|
| <ul> <li>Changed all instances of legacy terminology to controller and peripheral.</li> <li>Added WEBENCH links</li> <li>Moved the automotive device to a standalone data sheet (SNOSB22).</li> <li>Updated the data sheet to current TI format.</li> <li>Changed Bias Current (lin) from 3.7mA to 2mA.</li> <li>Changed Shutdown Current (lin) from 57uA to 48uA.</li> <li>Changed BOOST UVLO Hysteresis from 0.56V to 0.93V.</li> <li>Changed FB Bias Current from 17nA to 10nA.</li> </ul> Changes from Revision E (April 2013) to Revision F (April 2013) | <ul> <li>Updated the numbering format for tables, figures, and cross-references throughout the document</li> </ul> | 1              |
| <ul> <li>Changed all instances of legacy terminology to controller and peripheral.</li> <li>Added WEBENCH links</li> <li>Moved the automotive device to a standalone data sheet (SNOSB22).</li> <li>Updated the data sheet to current TI format.</li> <li>Changed Bias Current (lin) from 3.7mA to 2mA.</li> <li>Changed Shutdown Current (lin) from 57uA to 48uA.</li> <li>Changed BOOST UVLO Hysteresis from 0.56V to 0.93V.</li> <li>Changed FB Bias Current from 17nA to 10nA.</li> </ul> Changes from Revision E (April 2013) to Revision F (April 2013) | Deleted SIMPLE SWITCHER® branding from the data sheet  | 1              |
| <ul> <li>Moved the automotive device to a standalone data sheet (SNOSB22).</li> <li>Updated the data sheet to current TI format.</li> <li>Changed Bias Current (lin) from 3.7mA to 2mA.</li> <li>Changed Shutdown Current (lin) from 57uA to 48uA.</li> <li>Changed BOOST UVLO Hysteresis from 0.56V to 0.93V.</li> <li>Changed FB Bias Current from 17nA to 10nA.</li> </ul> Changes from Revision E (April 2013) to Revision F (April 2013)   |  |                |
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| <ul> <li>Updated the data sheet to current TI format.</li> <li>Changed Bias Current (lin) from 3.7mA to 2mA.</li> <li>Changed Shutdown Current (lin) from 57uA to 48uA.</li> <li>Changed BOOST UVLO Hysteresis from 0.56V to 0.93V.</li> <li>Changed FB Bias Current from 17nA to 10nA.</li> </ul> Changes from Revision E (April 2013) to Revision F (April 2013)  | Moved the automotive device to a standalone data sheet (SNOSB22)   | 1              |
| <ul> <li>Changed Bias Current (lin) from 3.7mA to 2mA</li> <li>Changed Shutdown Current (lin) from 57uA to 48uA</li> <li>Changed BOOST UVLO Hysteresis from 0.56V to 0.93V</li> <li>Changed FB Bias Current from 17nA to 10nA</li> </ul> Changes from Revision E (April 2013) to Revision F (April 2013)  |  |                |
| Changed BOOST UVLO Hysteresis from 0.56V to 0.93V.      Changed FB Bias Current from 17nA to 10nA.  Changes from Revision E (April 2013) to Revision F (April 2013)  Page   |  |                |
| Changed FB Bias Current from 17nA to 10nA   | Changed Shutdown Current (lin) from 57uA to 48uA   | <mark>6</mark> |
| Changes from Revision E (April 2013) to Revision F (April 2013) Page  | Changed BOOST UVLO Hysteresis from 0.56V to 0.93V  | 6              |
|   | Changed FB Bias Current from 17nA to 10nA  | 6              |
|   | Changes from Revision E (April 2013) to Revision F (April 2013)  | Page           |
|   |  |                |

## 10 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

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### PACKAGING INFORMATION

| Orderable part number | Status | Material type | Package   Pins  | Package qty   Carrier | RoHS (3) | Lead finish/<br>Ball material | MSL rating/<br>Peak reflow | Op temp (°C) | Part marking (6) |
|-----------------------|--------|---------------|-----------------|-----------------------|----------|-------------------------------|----------------------------|--------------|------------------|
| LM5574MT/NOPB         | Active | Production    | TSSOP (PW)   16 | 92   TUBE             | Yes      | NIPDAU   SN                   | Level-1-260C-UNLIM         | -40 to 125   | LM5574<br>MT     |
| LM5574MT/NOPB.A       | Active | Production    | TSSOP (PW)   16 | 92   TUBE             | Yes      | NIPDAU                        | Level-1-260C-UNLIM         | -40 to 125   | LM5574<br>MT     |
| LM5574MT/NOPB.B       | Active | Production    | TSSOP (PW)   16 | 92   TUBE             | Yes      | NIPDAU                        | Level-1-260C-UNLIM         | -40 to 125   | LM5574<br>MT     |
| LM5574MTX/NOPB        | Active | Production    | TSSOP (PW)   16 | 2500   LARGE T&R      | Yes      | NIPDAU   SN                   | Level-1-260C-UNLIM         | -40 to 125   | LM5574<br>MT     |
| LM5574MTX/NOPB.A      | Active | Production    | TSSOP (PW)   16 | 2500   LARGE T&R      | Yes      | NIPDAU                        | Level-1-260C-UNLIM         | -40 to 125   | LM5574<br>MT     |
| LM5574MTX/NOPB.B      | Active | Production    | TSSOP (PW)   16 | 2500   LARGE T&R      | Yes      | NIPDAU                        | Level-1-260C-UNLIM         | -40 to 125   | LM5574<br>MT     |

<sup>(1)</sup> Status: For more details on status, see our product life cycle.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

<sup>(2)</sup> Material type: When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

<sup>(3)</sup> RoHS values: Yes, No, RoHS Exempt. See the TI RoHS Statement for additional information and value definition.

<sup>(4)</sup> Lead finish/Ball material: Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

<sup>(5)</sup> MSL rating/Peak reflow: The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

<sup>(6)</sup> Part marking: There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.



## **PACKAGE OPTION ADDENDUM**

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#### OTHER QUALIFIED VERSIONS OF LM5574:

Automotive : LM5574-Q1

NOTE: Qualified Version Definitions:

Automotive - Q100 devices qualified for high-reliability automotive applications targeting zero defects

# **PACKAGE MATERIALS INFORMATION**

www.ti.com 23-May-2025

## TAPE AND REEL INFORMATION





|    | Dimension designed to accommodate the component width     |
|----|---|
| В0 | Dimension designed to accommodate the component length    |
| K0 | Dimension designed to accommodate the component thickness |
| W  | Overall width of the carrier tape                         |
| P1 | Pitch between successive cavity centers                   |

### QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



#### \*All dimensions are nominal

| Device         | Package<br>Type | Package<br>Drawing |    | SPQ  | Reel<br>Diameter<br>(mm) | Reel<br>Width<br>W1 (mm) | A0<br>(mm) | B0<br>(mm) | K0<br>(mm) | P1<br>(mm) | W<br>(mm) | Pin1<br>Quadrant |
|----------------|-----------------|--------------------|----|------|--------------------------|--------------------------|------------|------------|------------|------------|-----------|------------------|
| LM5574MTX/NOPB | TSSOP           | PW                 | 16 | 2500 | 330.0                    | 12.4                     | 6.95       | 5.6        | 1.6        | 8.0        | 12.0      | Q1               |

# **PACKAGE MATERIALS INFORMATION**

www.ti.com 23-May-2025



## \*All dimensions are nominal

| Ì | Device         | Package Type | Package Drawing | Pins | SPQ  | Length (mm) | Width (mm) | Height (mm) |  |
|---|----------------|--------------|-----------------|------|------|-------------|------------|-------------|--|
| ı | LM5574MTX/NOPB | TSSOP        | PW              | 16   | 2500 | 367.0       | 367.0      | 35.0        |  |

# **PACKAGE MATERIALS INFORMATION**

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## **TUBE**



\*All dimensions are nominal

| Device          | Package Name | Package Type | Pins | SPQ | L (mm) | W (mm) | T (µm) | B (mm) |
|-----------------|--------------|--------------|------|-----|--------|--------|--------|--------|
| LM5574MT/NOPB   | PW           | TSSOP        | 16   | 92  | 495    | 8      | 2514.6 | 4.06   |
| LM5574MT/NOPB   | PW           | TSSOP        | 16   | 92  | 530    | 10.2   | 3600   | 3.5    |
| LM5574MT/NOPB.A | PW           | TSSOP        | 16   | 92  | 530    | 10.2   | 3600   | 3.5    |
| LM5574MT/NOPB.A | PW           | TSSOP        | 16   | 92  | 495    | 8      | 2514.6 | 4.06   |
| LM5574MT/NOPB.B | PW           | TSSOP        | 16   | 92  | 530    | 10.2   | 3600   | 3.5    |
| LM5574MT/NOPB.B | PW           | TSSOP        | 16   | 92  | 495    | 8      | 2514.6 | 4.06   |



SMALL OUTLINE PACKAGE



### NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

  2. This drawing is subject to change without notice.

  3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
- 5. Reference JEDEC registration MO-153.



SMALL OUTLINE PACKAGE



NOTES: (continued)

- 6. Publication IPC-7351 may have alternate designs.
- 7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SMALL OUTLINE PACKAGE



NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.



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